

Profilometry

NNUM thematic seminar

Analysis

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Outline

- What is topography?
- Techniques for measuring topography
 - White Light Interferometry (WLI)
 - Atomic Force Microscopy (AFM)
- Summary: When to use which technique

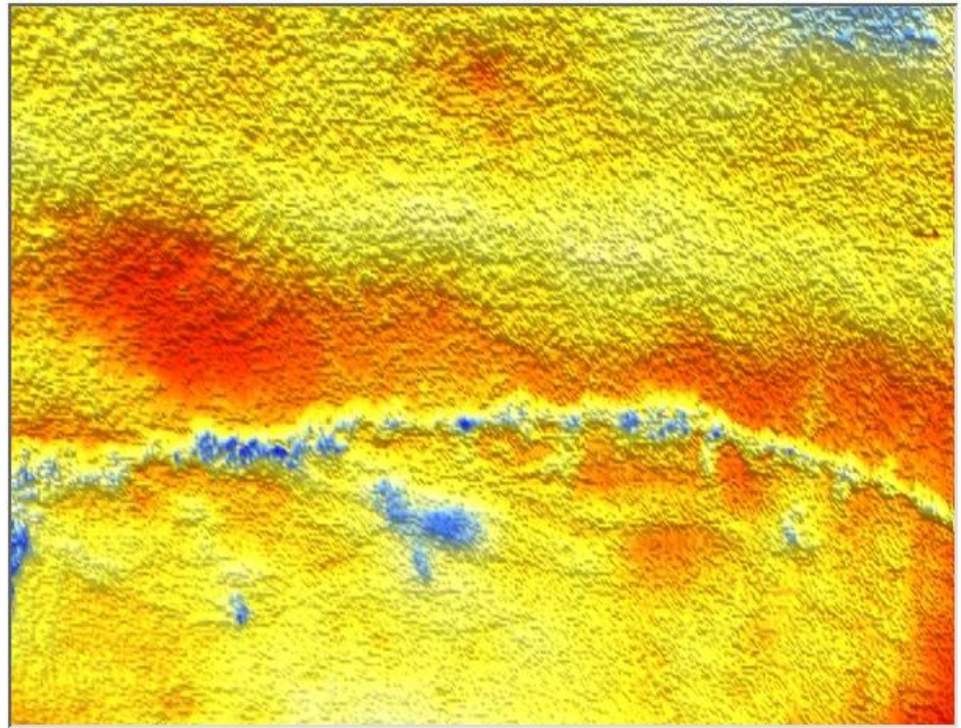
Topography

100 km
—



New Zealand
and surrounding sea bed

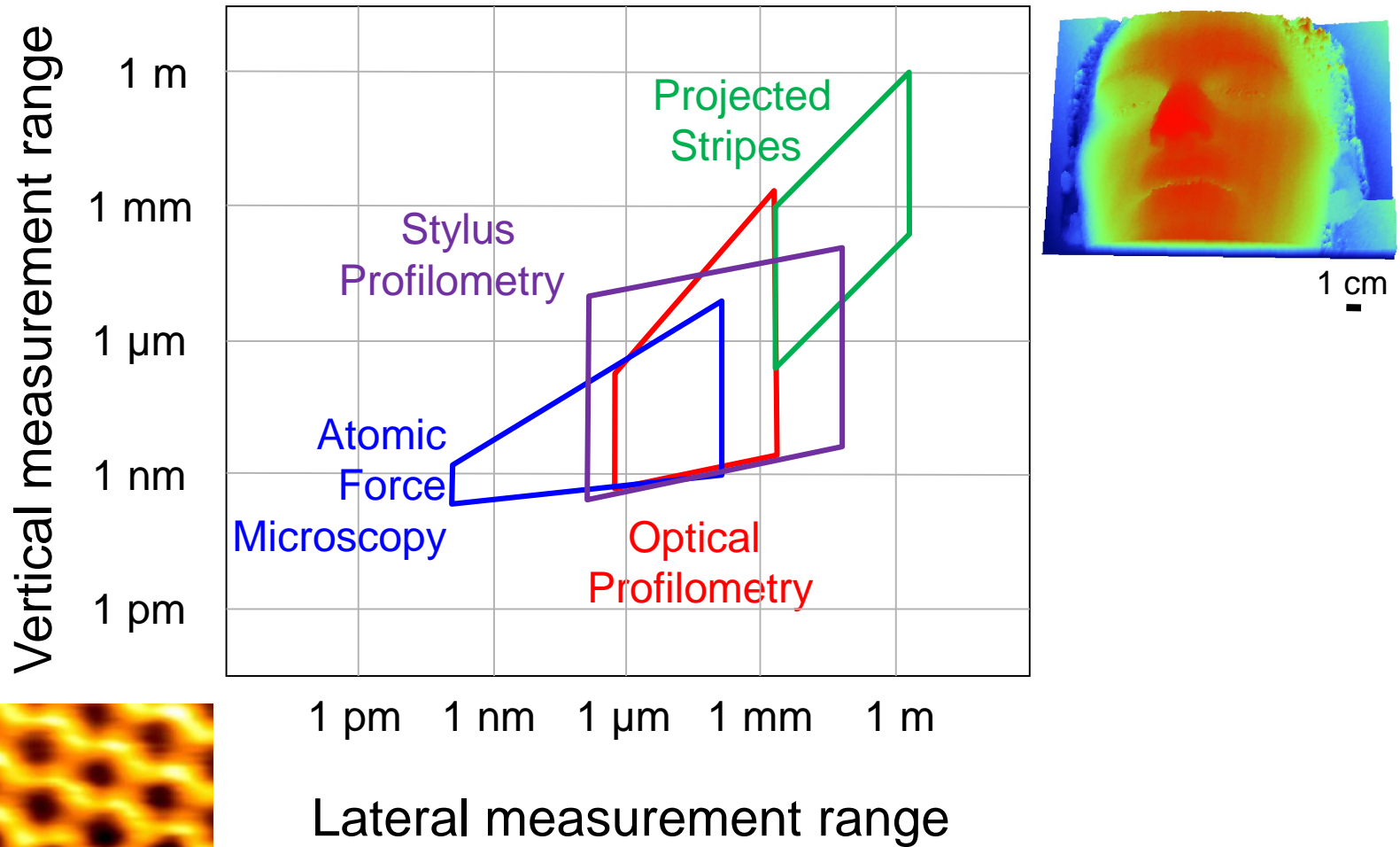
100 μ m
—



Surface of a tooth with an amalgam filling

Topography can be measured on different scales!

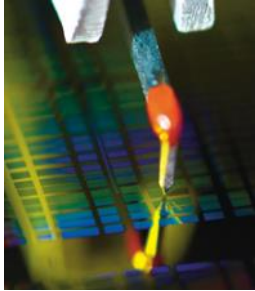
Techniques for measuring topography



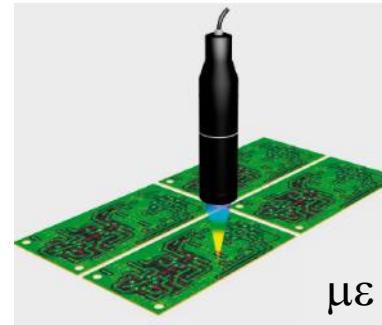
Profilometry (measuring topography)

- Stylus Profilometry

- 2D systems [Mitutoyo]
- 3D systems [Dektak]



Dektak



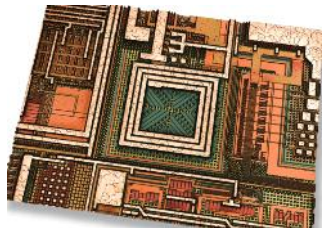
$\mu\epsilon$



Mitutoyo

- Optical Profilometry

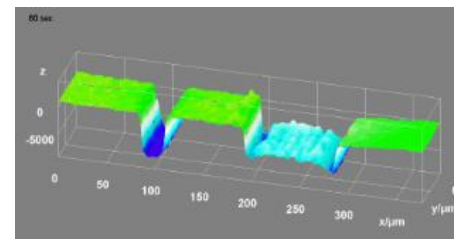
- Chromatic Confocal Sensing [Stil, $\mu\epsilon$]
- Confocal microscopy [Leica, Nikon]
- Focus variation [Sensofar]
- White Light Interferometry [Wyko, Zygo, Sensofar]
- Digital Holographic Microscopy [Lyncée Tec]
- etc.



Sensofar



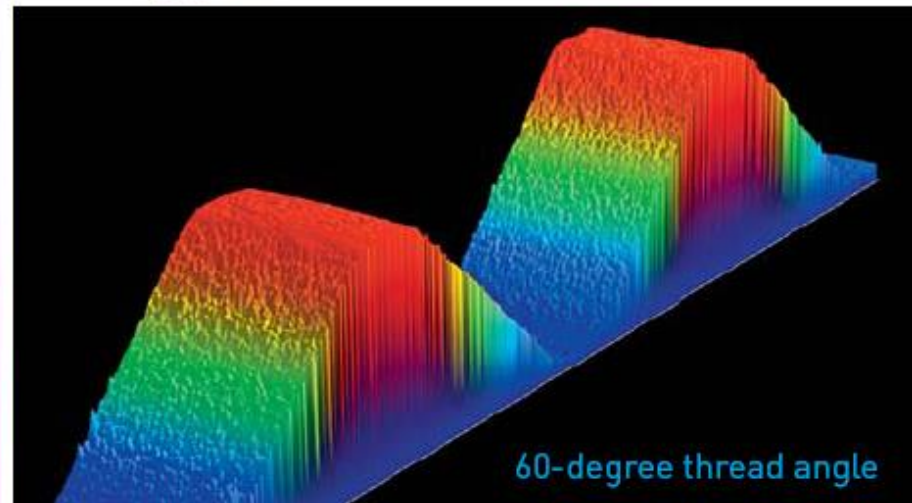
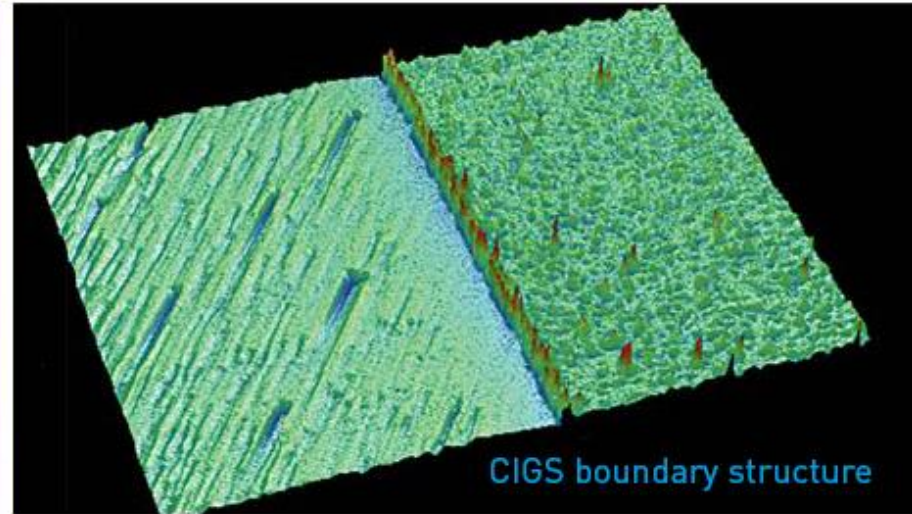
Nikon



Availability of instruments near you

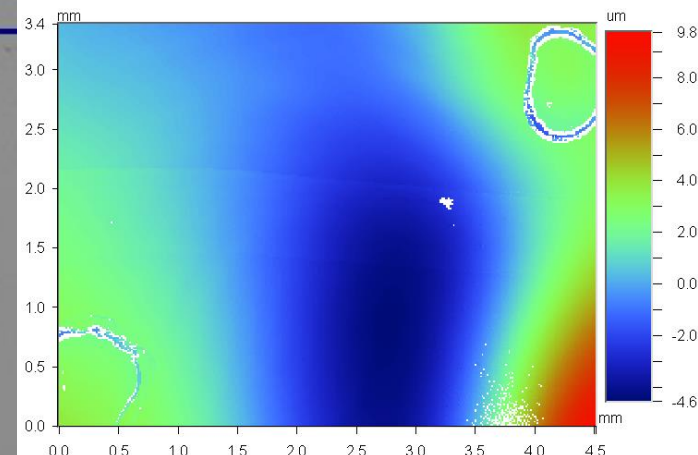
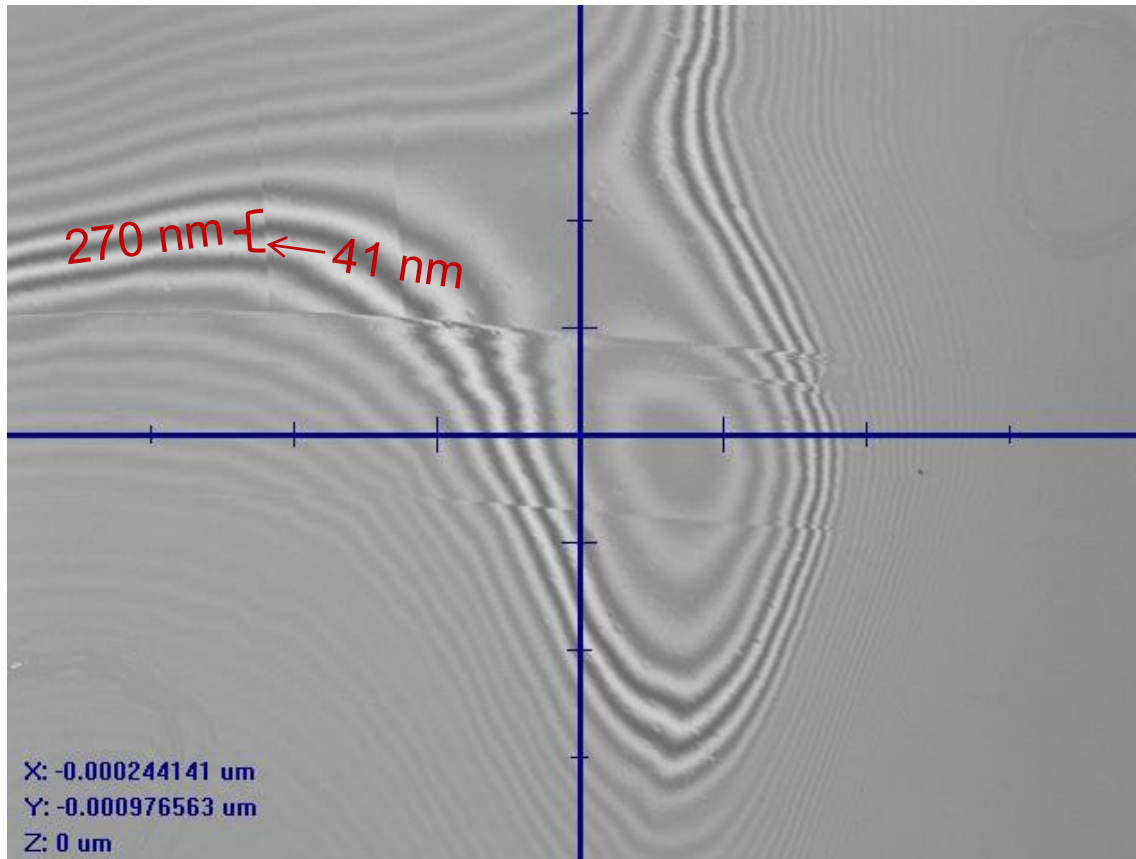
Location	Stylus Profilometer	Atomic Force Microscopes	Optical Profilometer
NTNU NanoLab	Dektak 150		
Lund Nano Lab	Dektak 6M		
Chalmers (NFL)	Tencor P15, Tencor AS500, Dektak	Dimension 3100 and ICON	Wyko NT1100
Uppsala (MSL)	Dektak 150, Dektak XT		Wyko NT1100
DanChip	Dektak 8, Dektak XTA	Dimension ICON PT	Sensofar
UiO	Dektak		
USN	Dektak		Wyko NT1100
Aalto	DektakXT, Alpha		
SINTEF		DI MultiMode	Wyko NT9800

White Light Interferometry (WLI) WYKO (Veeco/Bruker) optical profiler



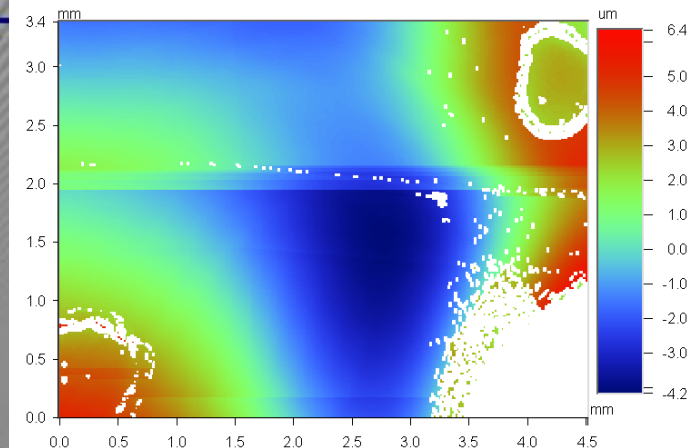
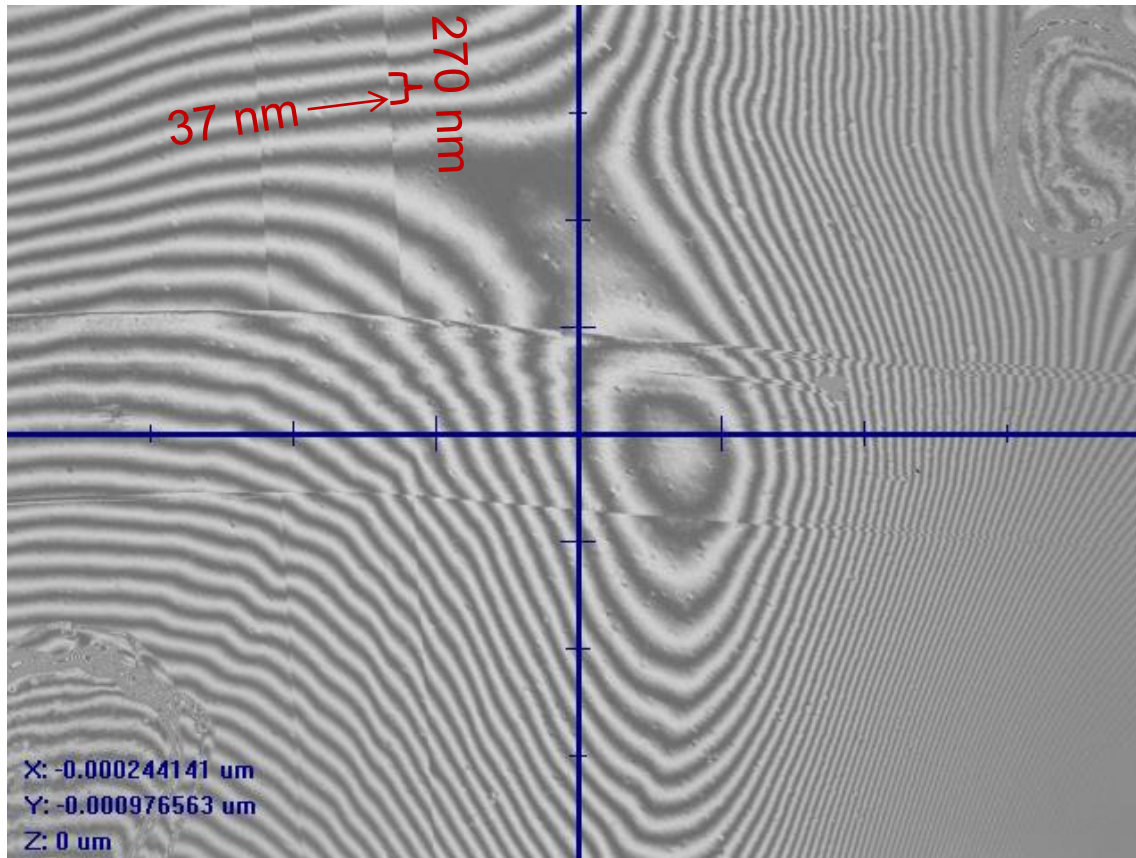
Vertical Scanning Interferometry (VSI)

- Height range: Several millimeters
- Noise level (3 nm) too high for very flat surfaces

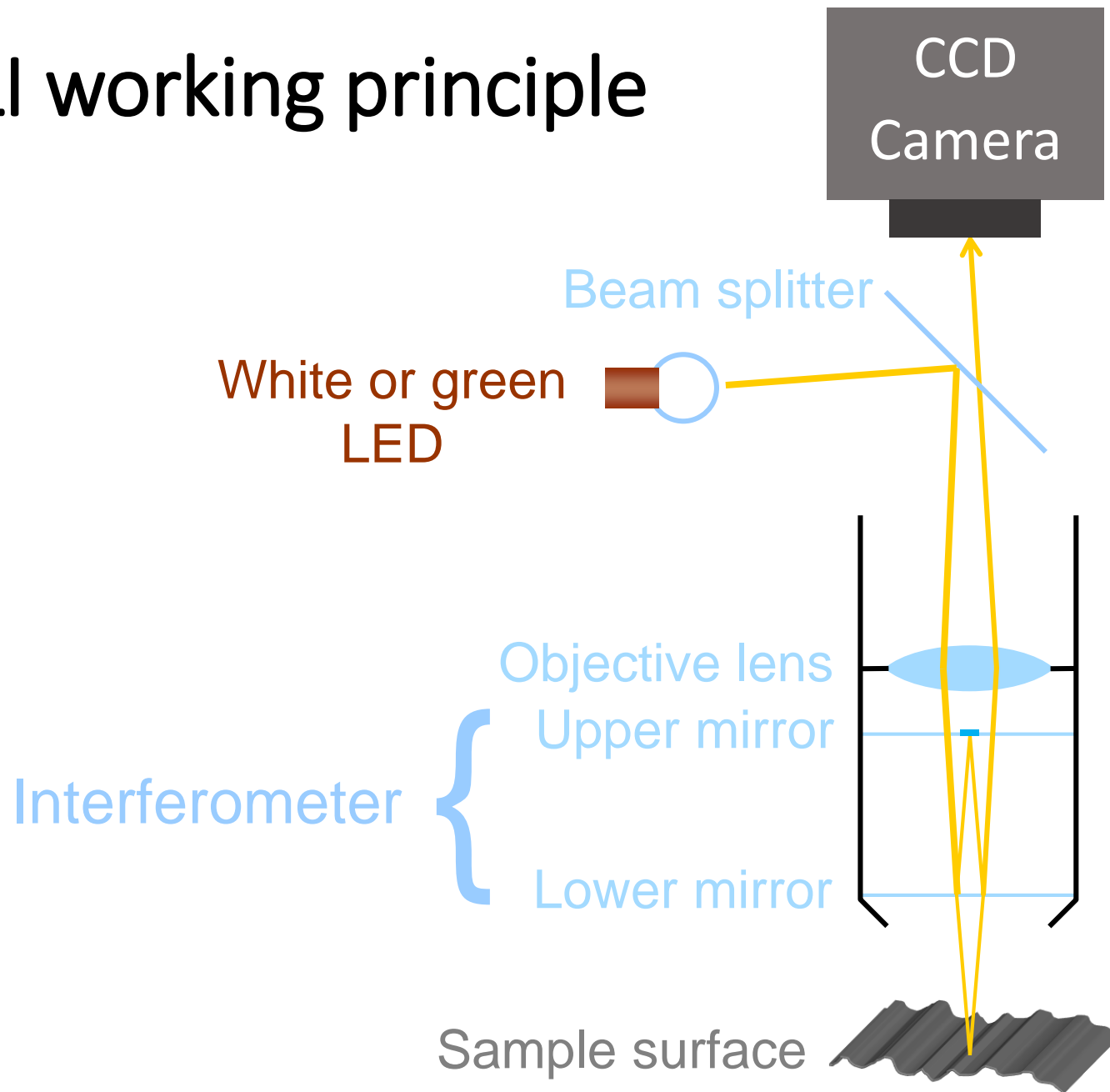


Phase Shifting Interferometry (PSI)

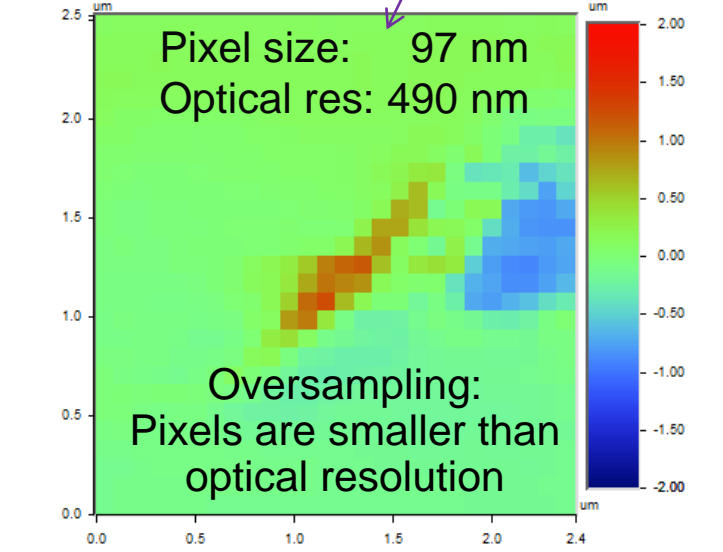
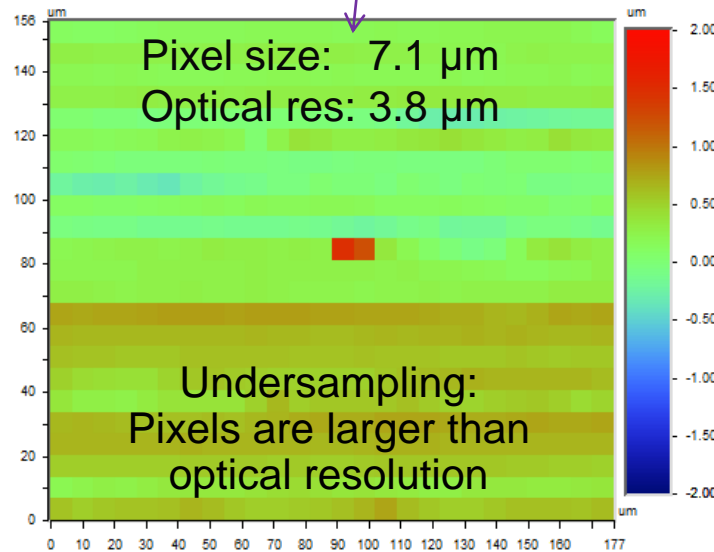
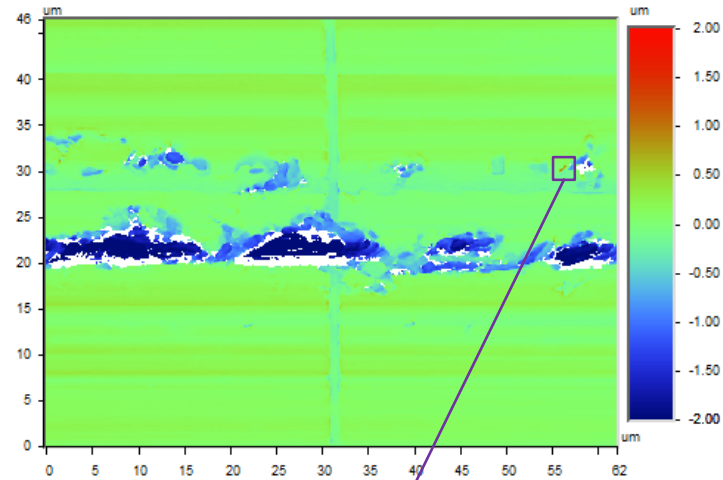
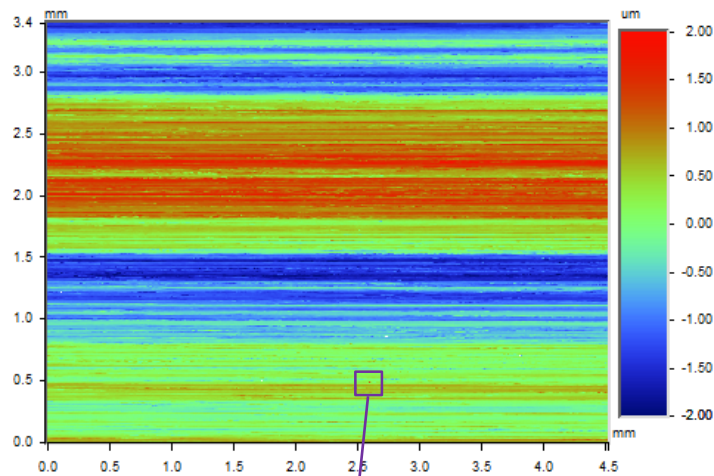
- Low noise level (0.3 nm), good for flat surfaces
- Can not measure sharp steps



WLI working principle



Pixel size vs. Optical resolution



Magnification: $2.5 \times 0.55x = 1.4x$

Magnification: $50 \times 2x = 100x$

Wyko NT9000 Series Optical Profiling Systems Objectives Chart

OBJECTIVE SPECIFICATIONS WITH STANDARD-RESOLUTION CAMERA

Magnification ²	Parfocal Set A Objectives ¹								Parfocal Set B Objectives			Non-Parfocal
	2.5XL	5X	5XL	10XBF	10X	20X	50X	100X	2XLWD	5XLWD	10XLWD	1.5XL
Interferometer Type	Michelson	Michelson	Michelson	Brightfield non-interferometric	Mirau	Mirau	Mirau	Mirau	Michelson	Michelson	Michelson	Michelson
Numerical Aperture	0.07	0.12	0.13	0.25	0.3	0.4	0.55	0.7	0.06	0.14	0.17	0.04
Working Distance (mm)	3.5	6.7	9.4	10.6	7.4	4.7	3.4	2	22	22	22	9.6
Optical Resolution (μm) ³	3.82	2.23	2.06	1.07	0.89	0.67	0.49	0.38	4.86	1.91	1.57	6.52
Practical Maximum Slope (deg) ⁴	1.9	3.8	3.8	—	7.6	14.2	26.7	34.8	1.5	6.4	7.6	1.2
Turret Mountable	Yes	Yes	Yes	Yes	Yes	Yes	Yes	Yes	No	No	No	No
Field of View, with magnification selector lens (mm x mm) ⁵												
0.55X	4.61 x 3.46	2.3 x 1.73	2.3 x 1.73	1.15 x 0.86	1.15 x 0.86	0.58 x 0.43	0.23 x 0.17	0.12 x 0.09	5.76 x 4.32	2.3 x 1.73	1.15 x 0.86	7.68 x 5.76
0.75X	3.38 x 2.53	1.69 x 1.27	1.69 x 1.27	0.84 x 0.63	0.84 x 0.63	0.42 x 0.32	0.17 x 0.13	0.09 x 0.07	4.22 x 3.17	1.69 x 1.27	0.84 x 0.63	5.63 x 4.22
1X	2.53 x 1.9	1.27 x 0.95	1.27 x 0.95	0.63 x 0.48	0.63 x 0.48	0.32 x 0.24	0.13 x 0.1	0.07 x 0.05	3.17 x 2.38	1.27 x 0.95	0.63 x 0.48	4.22 x 3.17
1.5X	1.69 x 1.27	0.84 x 0.63	0.84 x 0.63	0.42 x 0.32	0.42 x 0.32	0.21 x 0.16	0.08 x 0.06	0.04 x 0.03	2.11 x 1.58	0.84 x 0.63	0.42 x 0.32	2.82 x 2.11
2X	1.27 x 0.95	0.63 x 0.48	0.63 x 0.48	0.32 x 0.24	0.32 x 0.24	0.16 x 0.12	0.06 x 0.05	0.03 x 0.03	1.58 x 1.19	0.63 x 0.48	0.32 x 0.24	2.11 x 1.58
Spatial Sampling, with magnification selector lens (μm) ⁵												
0.55X	7.2	3.6	3.6	1.8	1.8	0.9	0.36	0.18	9	3.6	1.8	12
0.75X	5.28	2.64	2.64	1.32	1.32	0.66	0.26	0.13	6.6	2.64	1.32	8.8
1X	3.96	1.98	1.98	0.99	0.99	0.5	0.2	0.1	4.95	1.98	0.99	6.6
1.5X	2.64	1.32	1.32	0.66	0.66	0.33	0.13	0.07	3.3	1.32	0.66	4.4
2X	1.98	0.99	0.99	0.5	0.5	0.25	0.1	0.05	2.48	0.99	0.5	3.3

Undersampling

Oversampling

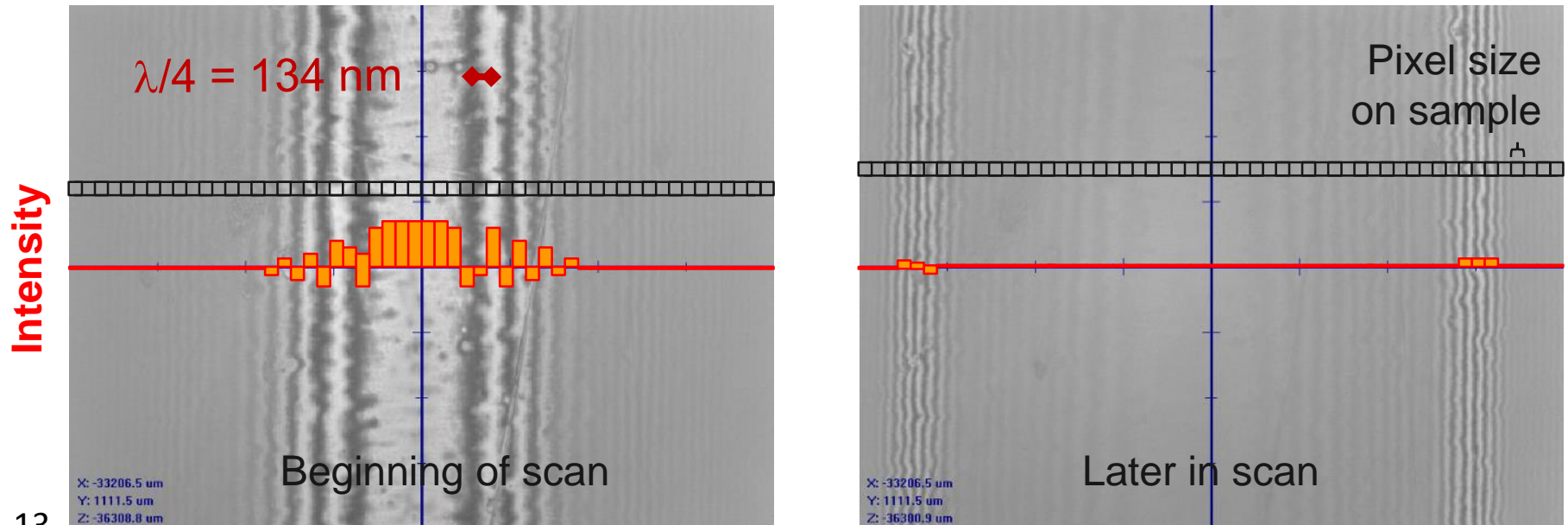
¹Objectives are parfocal within their respective set (i.e., set A objectives are parfocal to each other, and set B objectives are parfocal to each other).
²Chart specifications are based on nominal magnifications. Actual magnification is determined by the system geometry and the camera sensor size.
³Optical resolution based on Sparrow Criteria at 535nm.
⁴As measured on an optically smooth surface and 1X magnification selector lens. Practical slope limit for non-specular surfaces may be higher.
⁵Field of view and spatial sampling are based on full resolution 640 x 480 pixels measurement array, 9.9μm x 9.9μm pixel size.

Limit for the surface steepness

- If a dark and bright fringe fills the same pixel, the average is grey so the interference is not detected.
- The **practical maximum slope** gives the steepest surface tilt that can be measured:

$$\theta \leq \arctan(\Delta z / \Delta x) = \arctan(134 \text{ nm} / \text{pixelsize})$$

Cylindrical sample surface



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Optical Resolution (μm) ³	3.82	2.23	2.06	1.07	0.89	0.67	0.49	0.38	4.86	1.91	1.57	6.52
Practical Maximum Slope (deg) ⁴	1.9	3.8	3.8	—	7.6	14.2	26.7	34.8	1.5	6.4	7.6	1.2
Turret Mountable	Yes	Yes	Yes	Yes	Yes	Yes	Yes	Yes	No	No	No	No

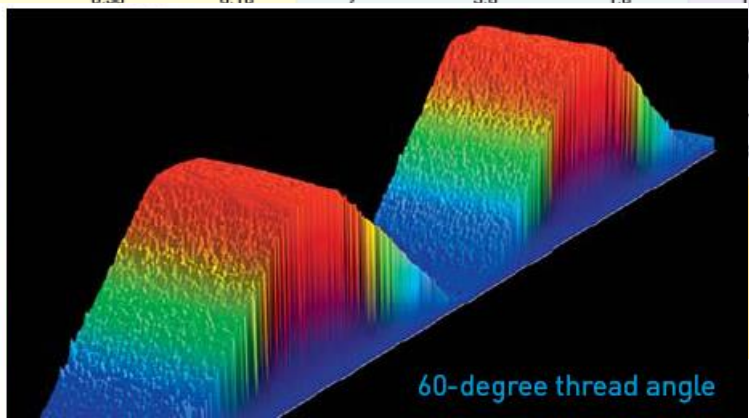
Practical maximum slope between 2° and 35°

You need a high-magnification lens to see steep facets

Field of View, with magnification selector lens (mm x mm) ⁵	2.5XL	5X	5XL	10XBF	10X	20X	50X	100X	2XLWD	5XLWD	10XLWD	1.5XL
0.55X	4.61 x 3.46	2.3 x 1.73	2.3 x 1.73	1.15 x 0.86	1.15 x 0.86	0.58 x 0.43	0.23 x 0.17	0.12 x 0.09	5.76 x 4.32	2.3 x 1.73	1.15 x 0.86	7.68 x 5.76
0.75X												4.22
1X												3.17
1.5X												2.11
2X	1.27 x 0.95	0.63 x 0.48	0.63 x 0.48	0.32 x 0.24	0.32 x 0.24	0.16 x 0.12	0.06 x 0.05	0.03 x 0.03	1.58 x 1.19	0.63 x 0.48	0.32 x 0.24	2.11 x 1.58

Spatial Sampling, with magnification selector lens (μm) ⁶	2.5XL	5X	5XL	10XBF	10X	20X	50X	100X	2XLWD	5XLWD	10XLWD	1.5XL
0.55X	7.2	3.6	3.6	1.8	1.8	0.9	0.36	0.18	9	3.6	1.8	12
0.75X	5.28	2.64	2.64	1.32	1.32	0.66						8
1X	3.96	1.98	1.98	0.99	0.99	0.5						6
1.5X												4
2X												3

If the surface has a high local roughness, you may be able to measure steeper slopes



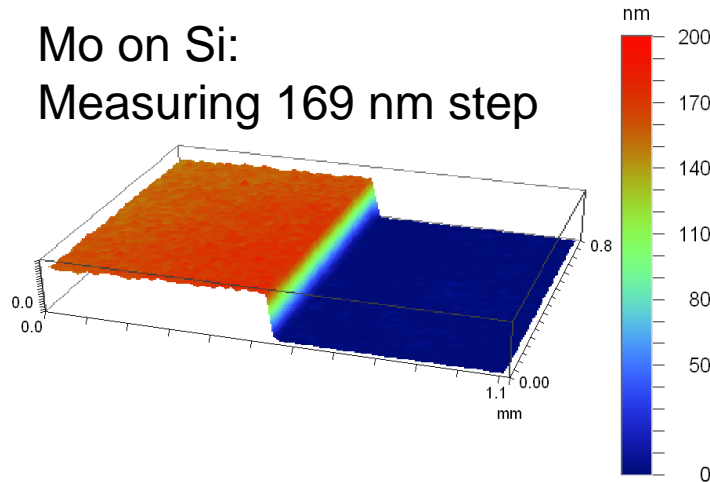
¹Objectives as specified in the chart
²Chart specifications
³Optical resolution
⁴As measured
⁵Field of view
⁶Wyko is a registered trademark of Wyko

Wrong step height if different materials

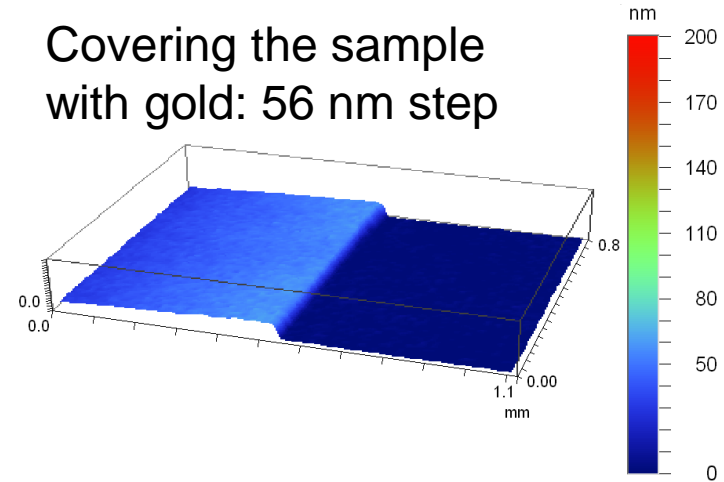
Be careful when measuring

- Transparent materials on a substrate (May give reflections from both surfaces)
- Different materials within the same image (Phase changes upon reflection)

Mo on Si:
Measuring 169 nm step



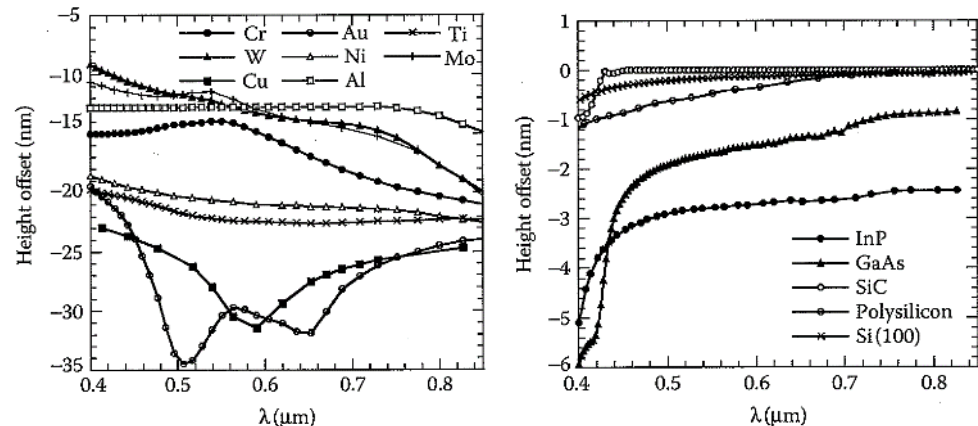
Covering the sample
with gold: 56 nm step



Height offset from material:

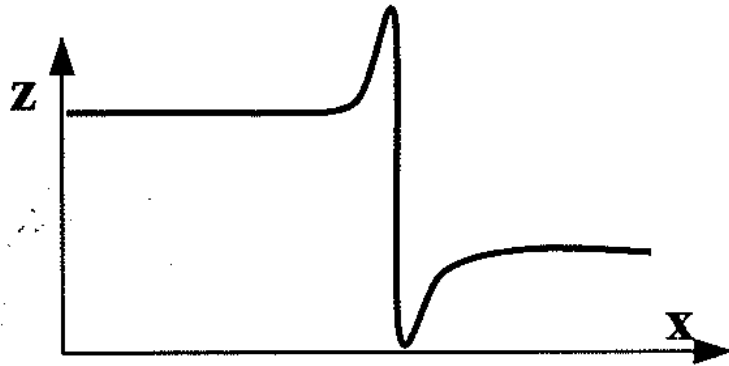
$$h_{\text{offset}} = \frac{\lambda}{4\pi} \varphi_s(\theta = 0) = \frac{\lambda}{4\pi} \arctan \left[\frac{2\kappa}{1 - n^2 - \kappa^2} \right]$$

n and κ are real part and imaginary part of refractive index

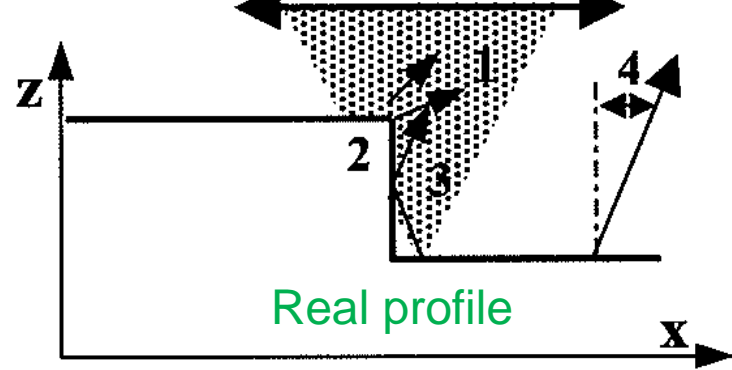


Beware of artefacts near sharp steps

Measured profile



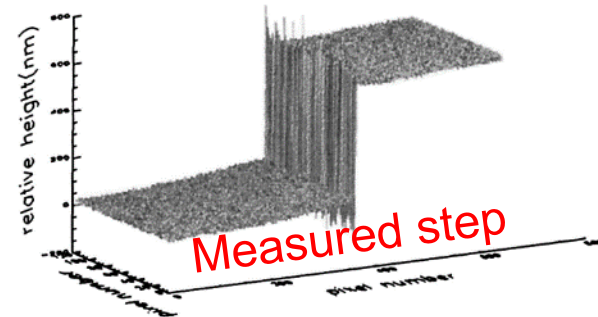
Objective



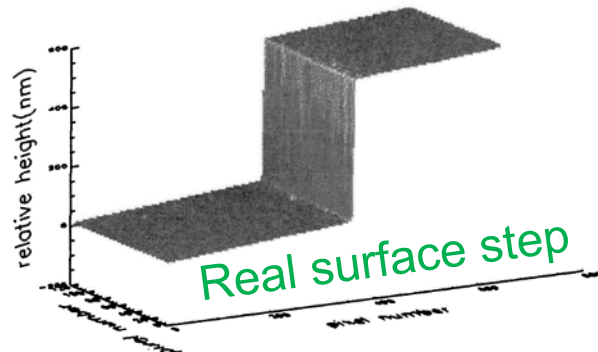
Real profile

Step height profile display
batwings due to

- Light diffraction
- Shadowing
- Light reflection
- Lateral translation/tilting during vertical scanning



Measured step



Real surface step

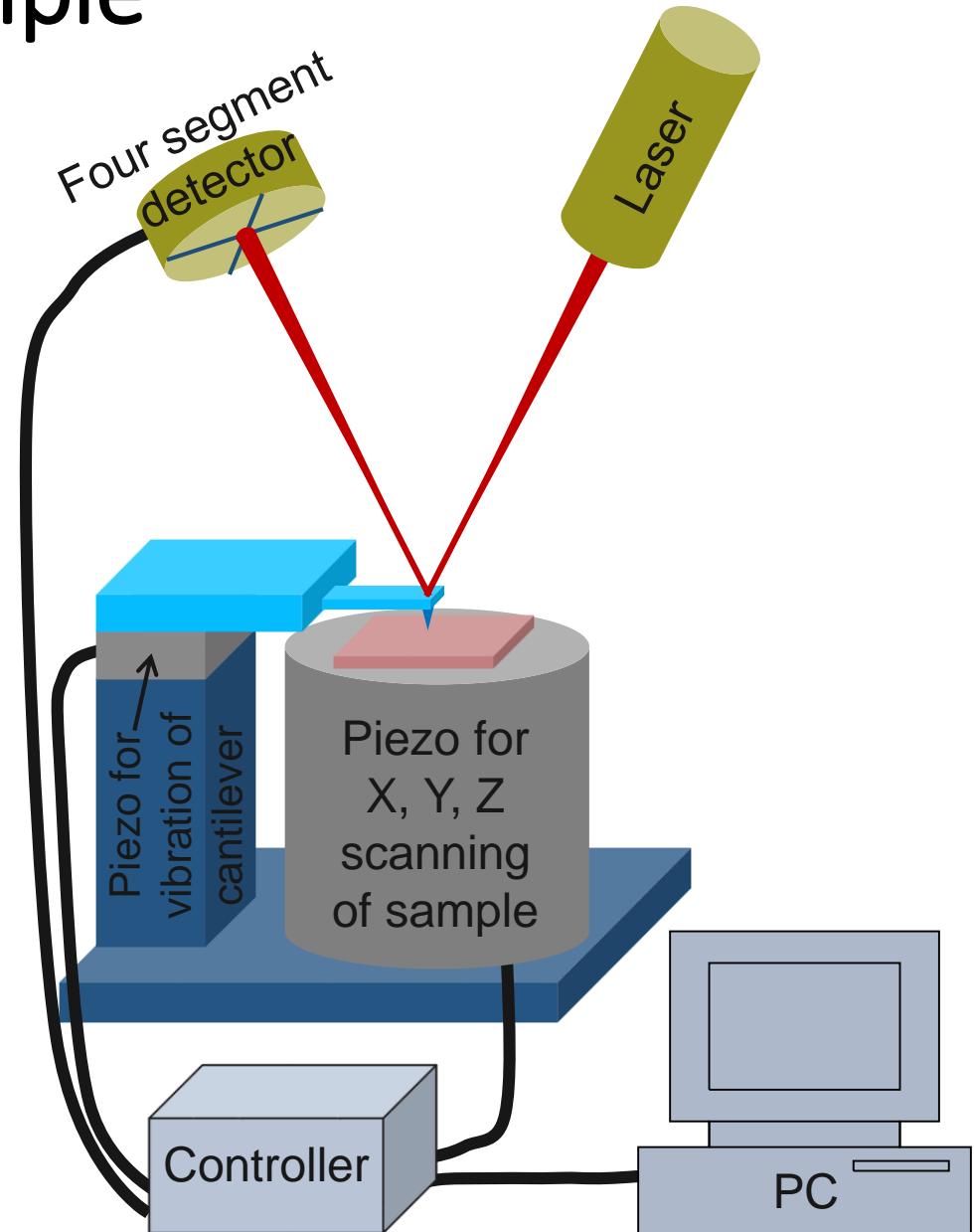
Atomic Force Microscopy (AFM)

Live demo of intermolecular forces

AFM working principle



AFM with optical microscope



Cantilevers and tips

- Many types exist, for different applications

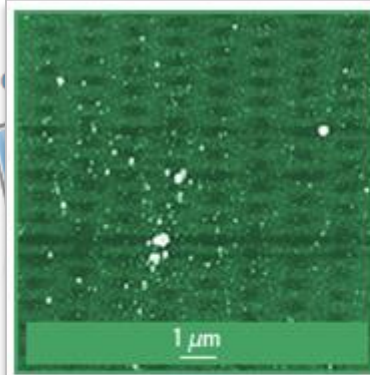
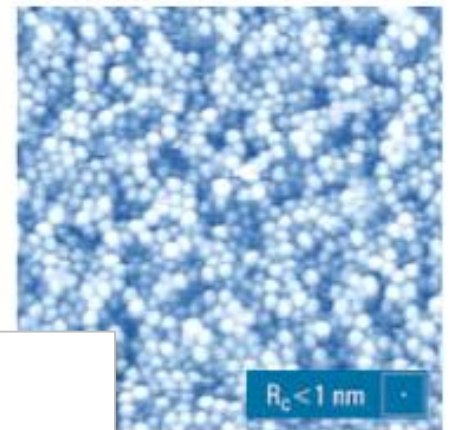
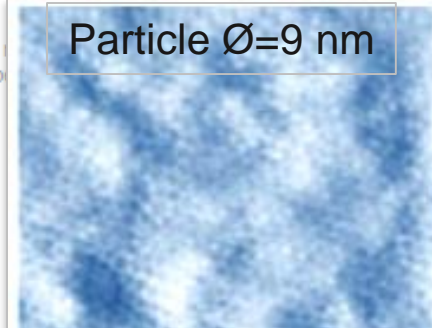
HIGH RESOLUTION



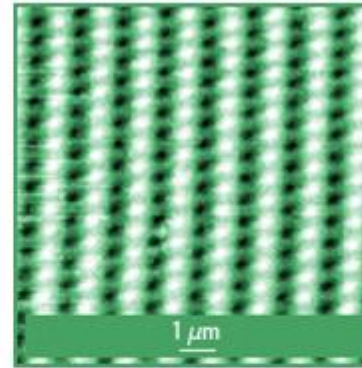
Lateral resolution below 1 nm
For scanning small areas below 250 nm at 512 points.

1 nm radius
multiple diamond-like tips
HIRES-C

1 nm radius
tungsten tip
HIRES-W



Height image obtained in Tapping mode.



MFM map of the same area showing magnetic domain structure.

Magnetic

probe in Tapping mode. The molecules are resolved. Tip radius $r \sim 1$ nm.

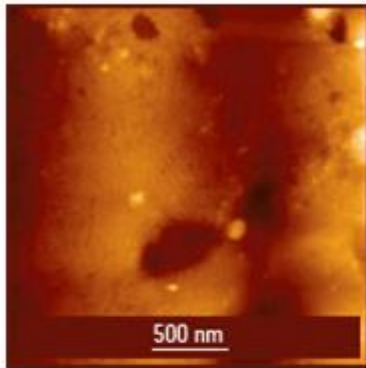
- 70..150 kHz (0.6..1.8 N/m)
- 20..40 kHz (0.3..0.6 N/m)
- 20..40 kHz (0.03..0.08 N/m)

TRIANGULAR

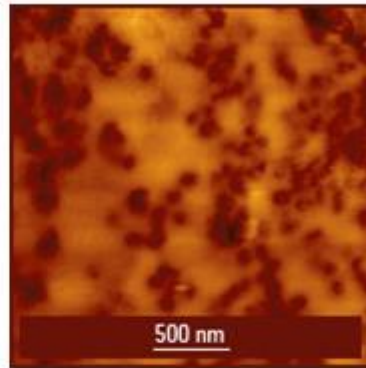


- 330 kHz (48 N/m)
- 60 kHz (3.0 N/m)
- 210 kHz (17 N/m)
- 25 kHz (1.0 N/m)
- 155 kHz (6.0 N/m)
- 28 kHz (0.35 N/m)
- 105 kHz (2.0 N/m)
- 12 kHz (0.12 N/m)

For imaging of electric properties of materials in ambient conditions, probes with special conducting coatings are usually used.



Height image obtained in Tapping mode.



EFM map of the same area.

Electric

Height and phase images of the rubber-modified isotactic polypropylene filled with carbon black. The images were obtained in Electric Force Microscopy mode using NSC14 probes coated with Pt. Images courtesy of S. Magonov (Veeco).

obtained using Co-Cr cantilevers. The structure is interfered by laser impulses. Images are courtesy of

40 nm radius tip
Ti-Pt coated

50 nm radius tip
Cr-Au coated

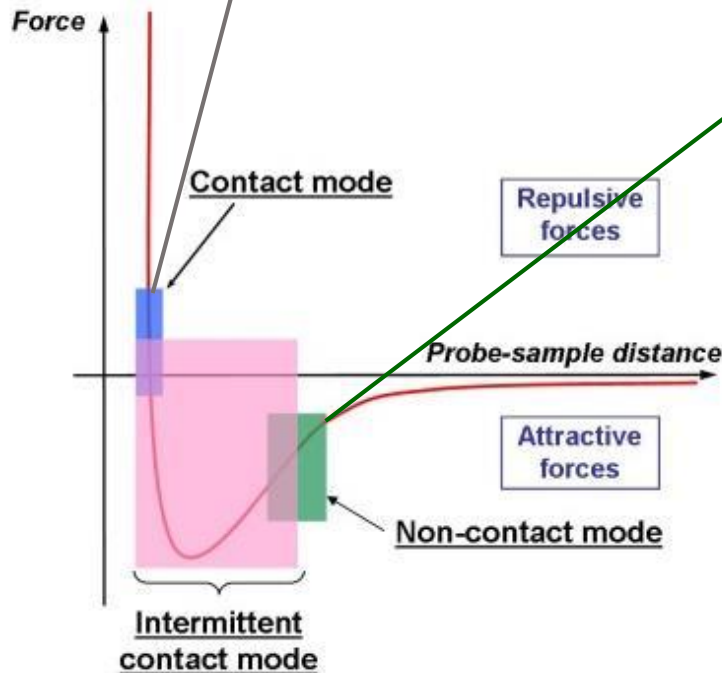
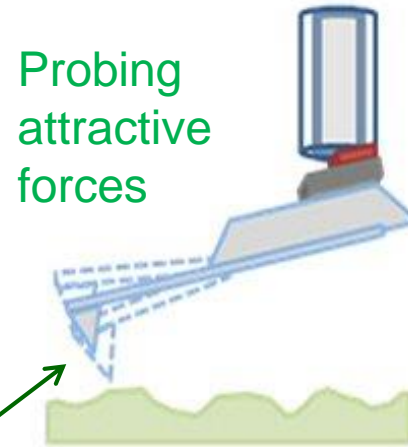
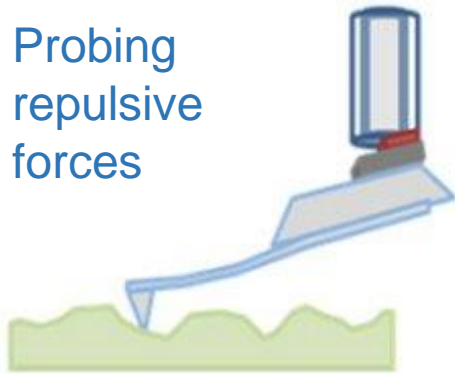
MAGNETIC



Probes with magnetic coating for MFM.

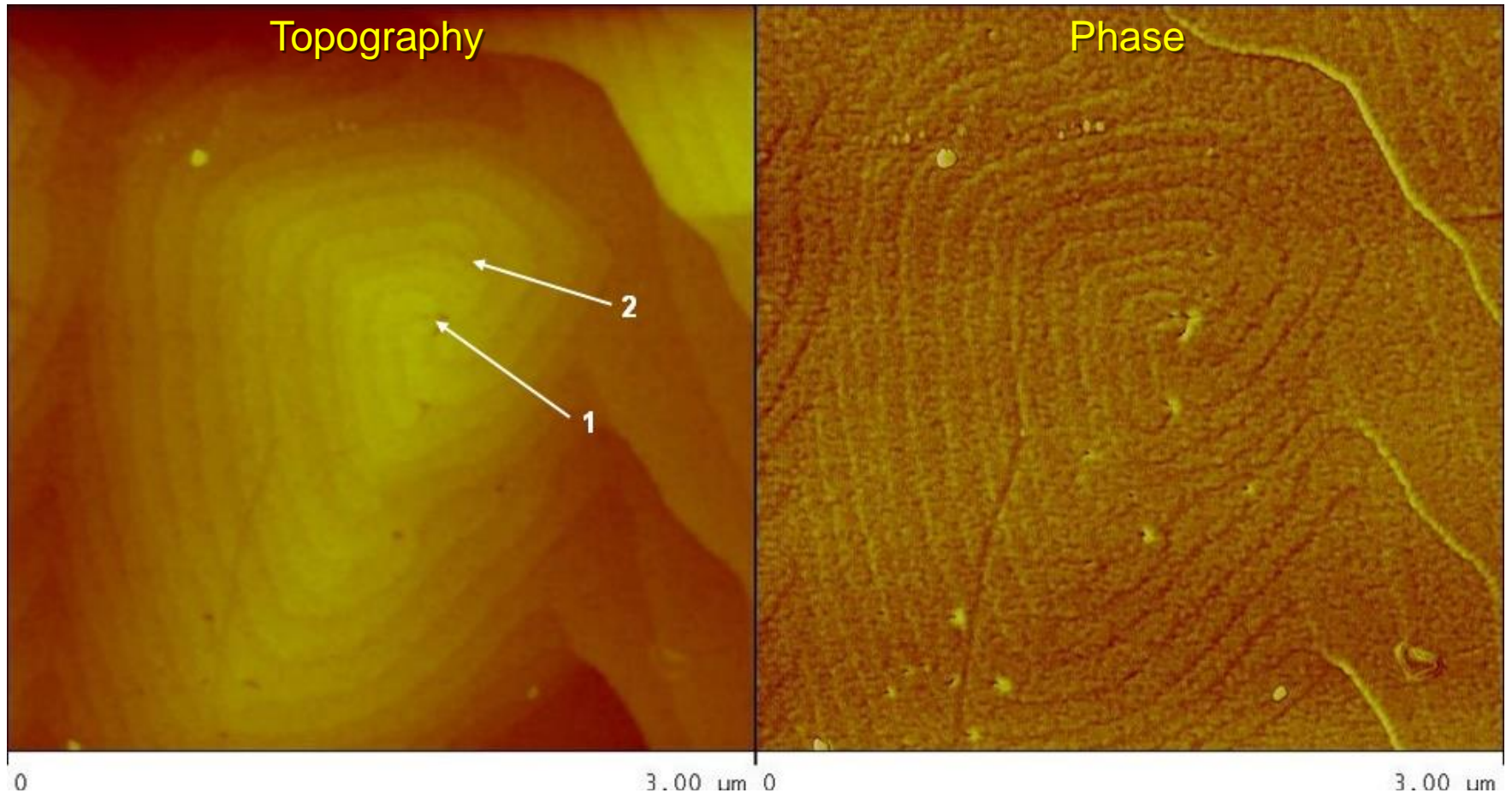
90 nm radius magnetic tip
Co-Cr coated

Contact mode vs. Non-contact mode



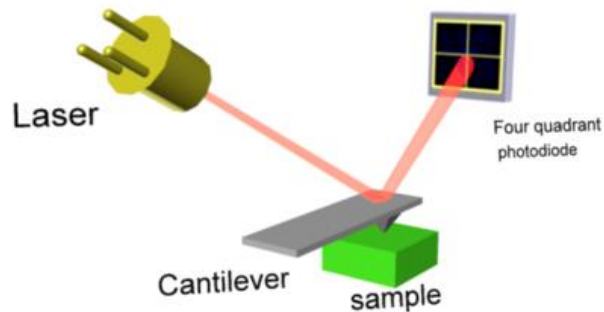
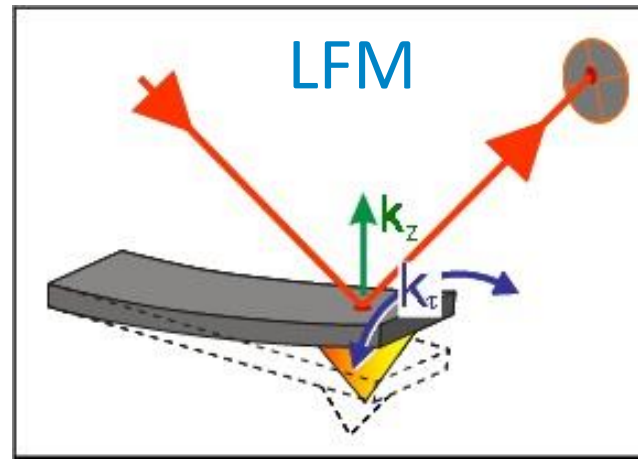
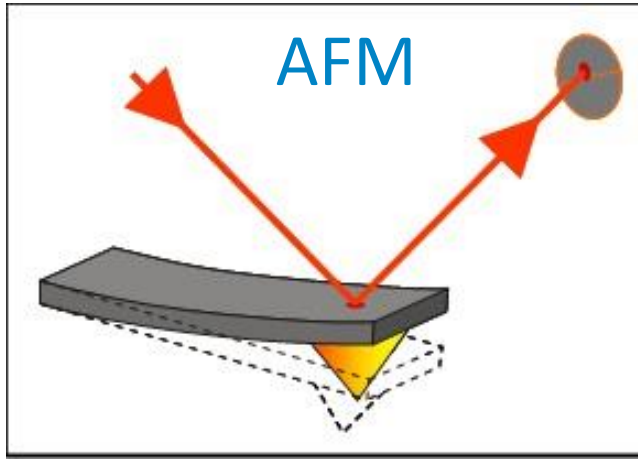
- Contact mode used for hard surfaces
- Non-contact mode for soft surfaces or to detect softness contrast

Non-contact mode gives both Topography and Phase images

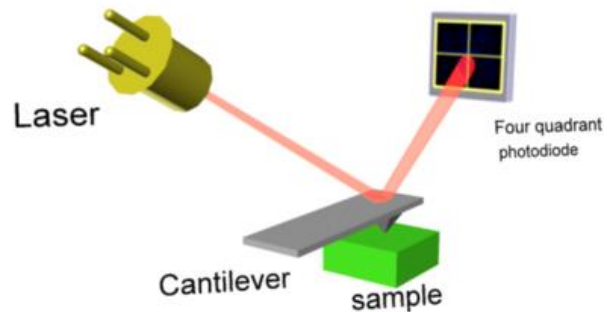


Displaying the same data in different ways:
The absolute height and its derivative

Lateral Force Microscopy (LFM)



Measuring topography

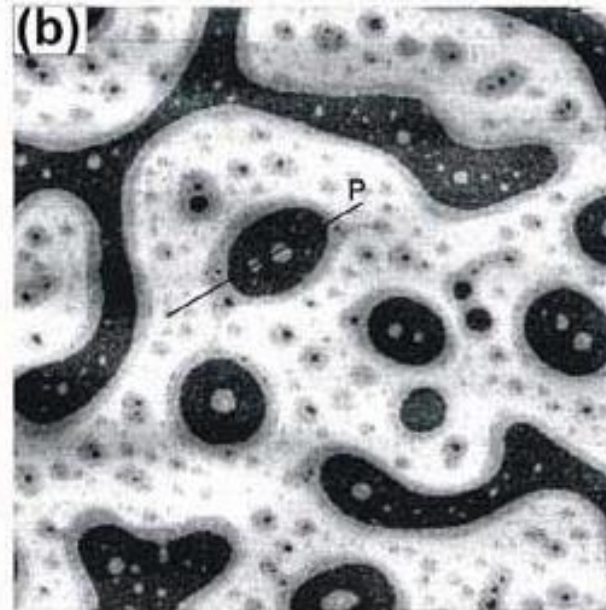
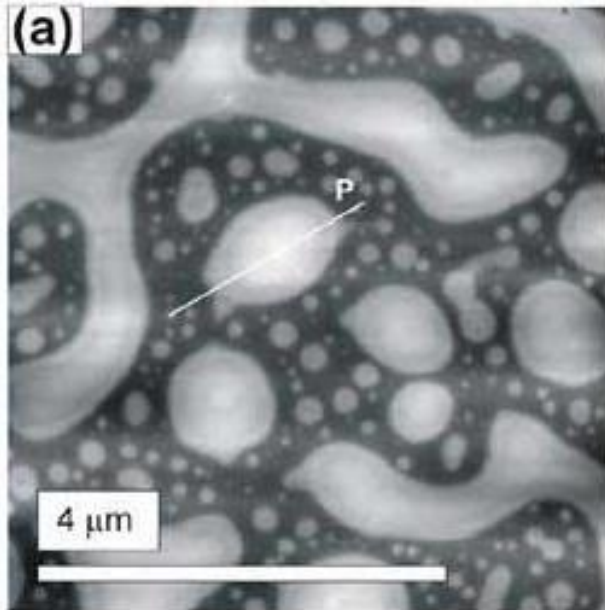


Measuring frictional forces

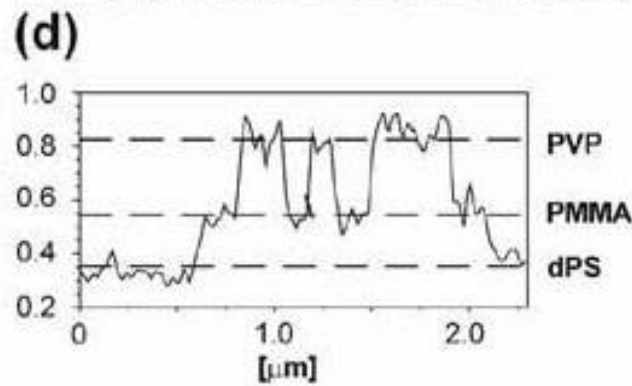
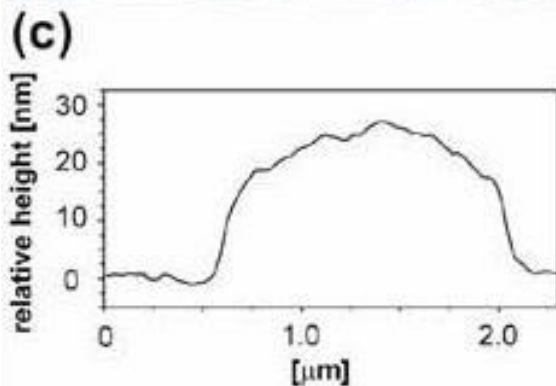
Lateral Force Microscopy (LFM)

AFM

LFM



Useful for distinguishing between polymer materials



Using AFM to study MEMS device

HiVe Master student Huy Quoc Nguyen came to Oslo to use the AFM at SINTEF Materials and Chemistry

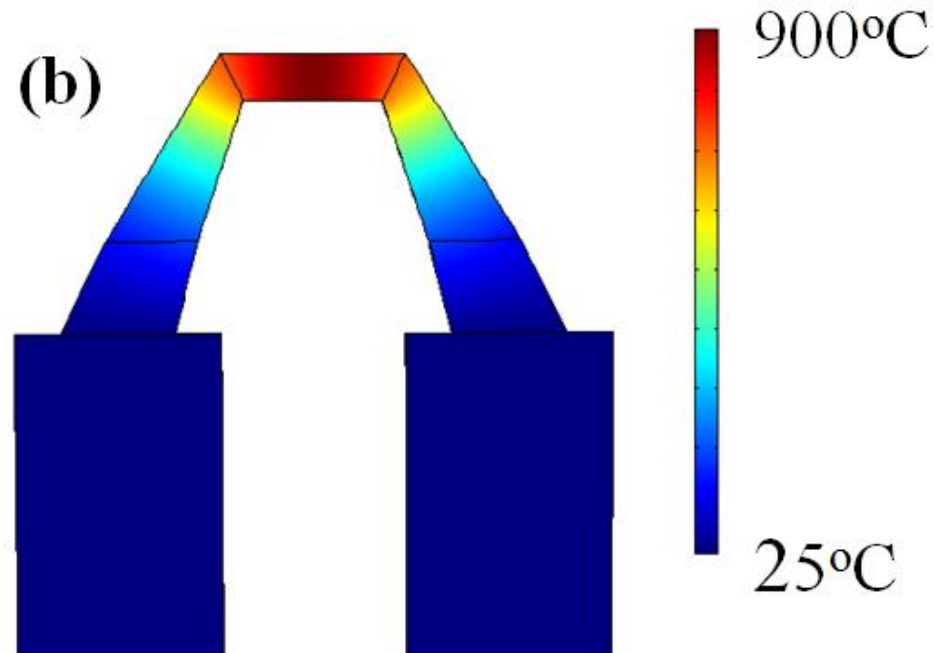
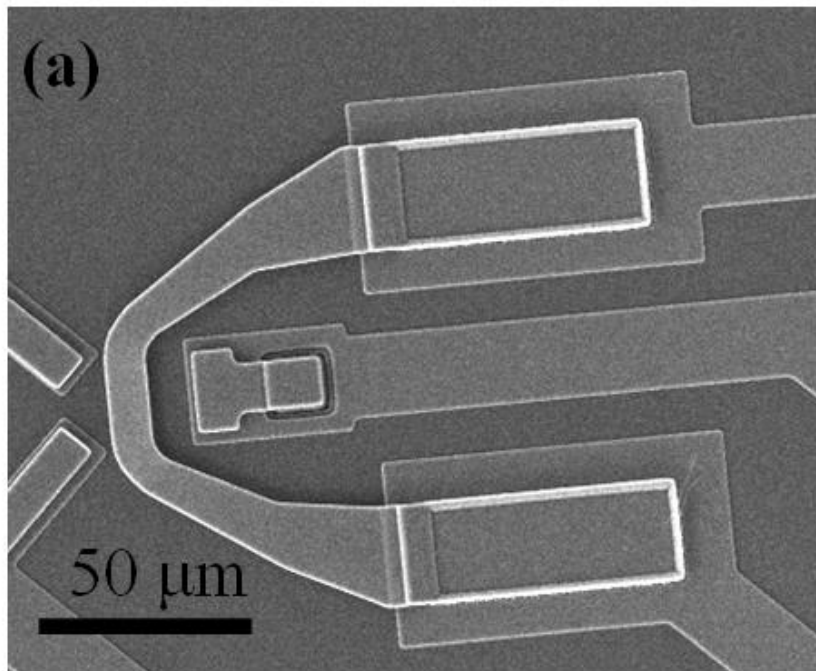


Figure 1: (a) Microheater geometry, (b) Simulation of temperature gradient on the surface of the microheater.

Using AFM to study MEMS device

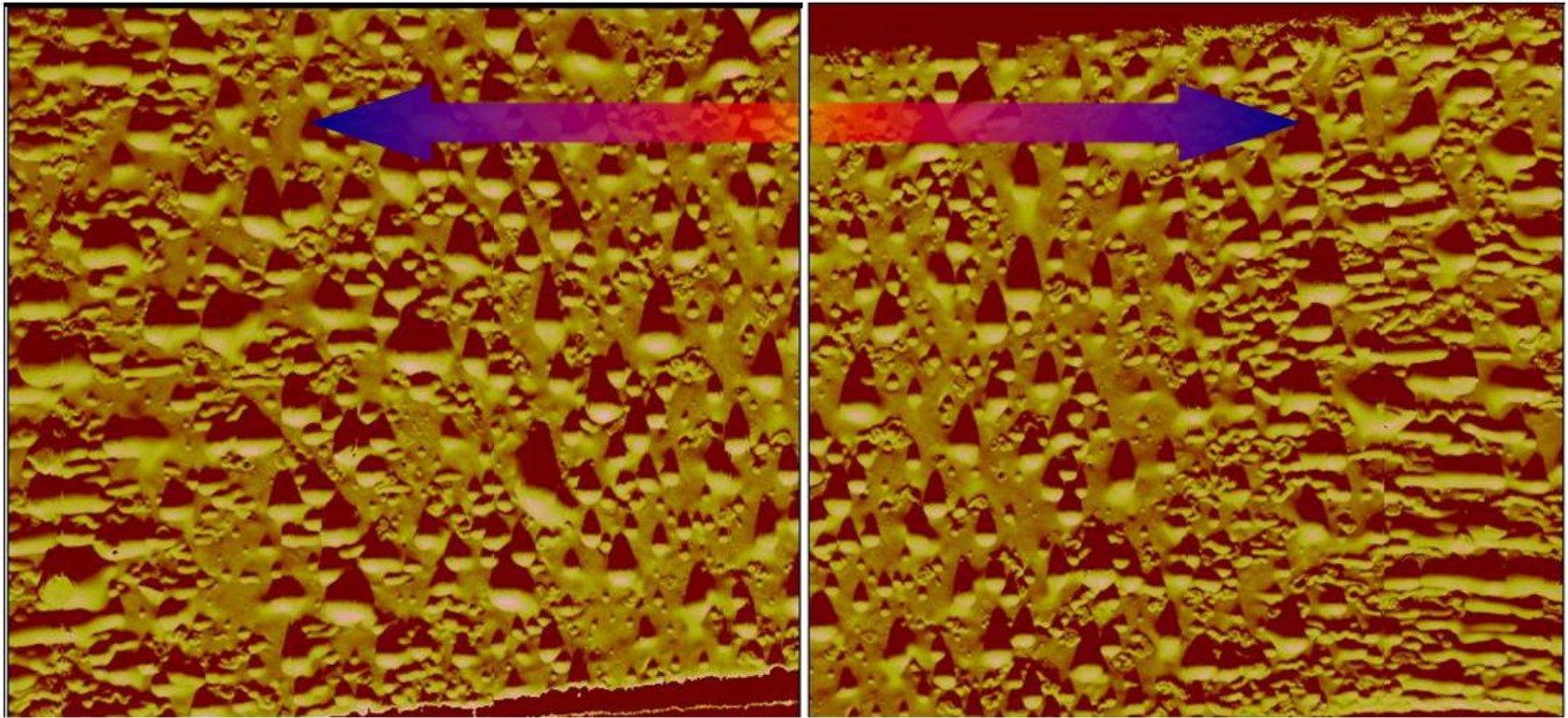
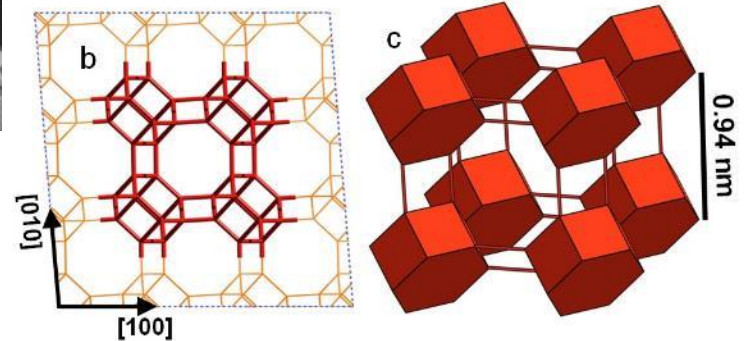
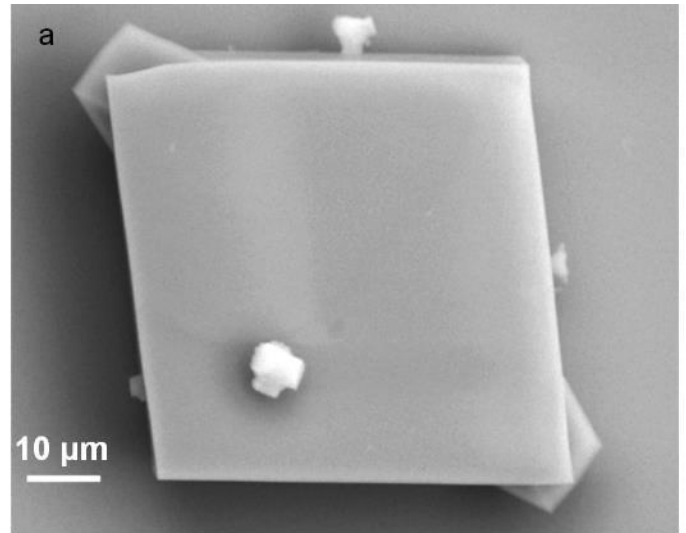
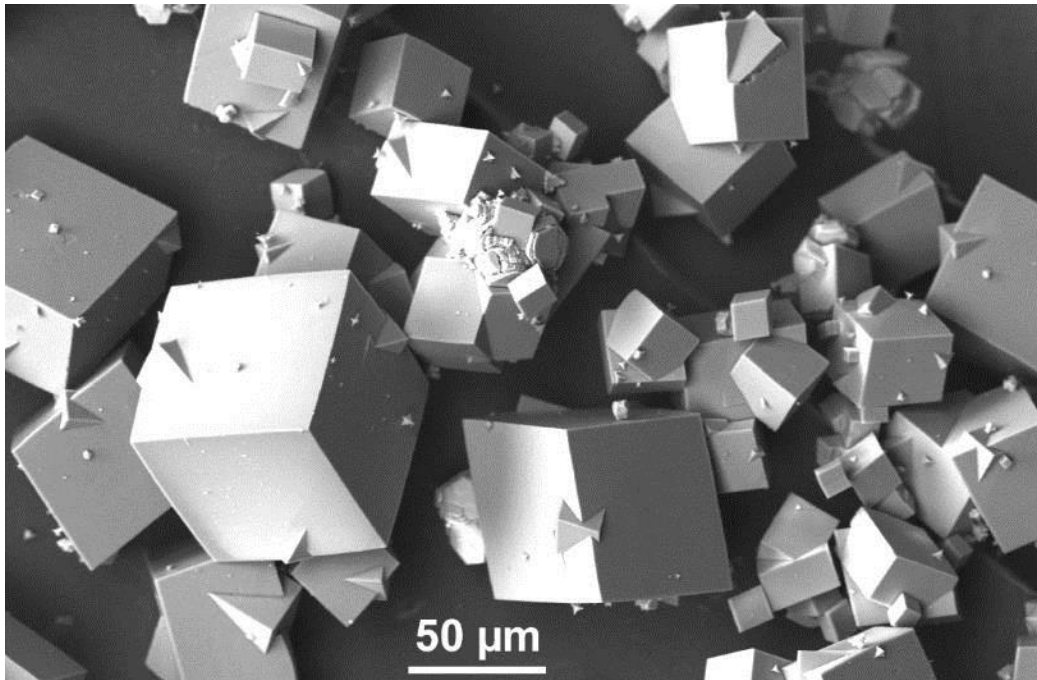


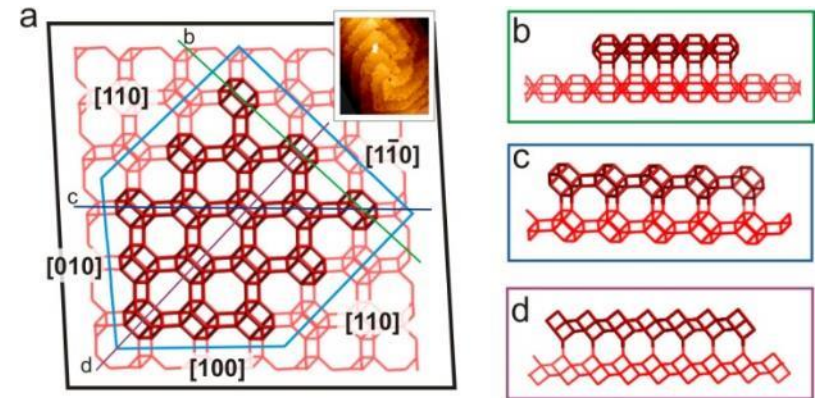
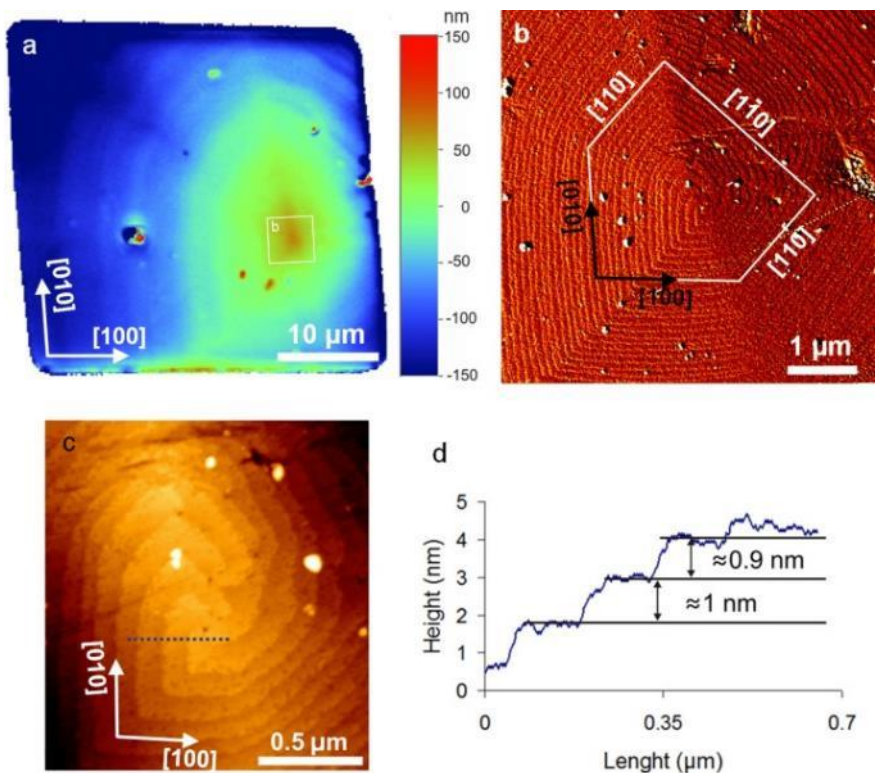
Figure 4: $10\ \mu\text{m} \times 10\ \mu\text{m}$ AFM phase contrast images showing that nanoparticles move away from the hot spot in the middle of the bridge following the temperature gradient.

WLI + AFM on SAPO-34 catalyst grains



- SEM images show nearly cubic grains
- The shape can be related to the crystal structure

WLI + AFM on SAPO-34 catalyst grains



Relating the pentagonal growth spirals to structural details

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Growth mechanisms in SAPO-34 studied by White Light Interferometry and Atomic Force Microscopy

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When to use which technique?

- Use AFM when you
 - need to see lateral details $< 1 \mu\text{m}$
 - need info on surface softness or friction
 - need info on magnetic or electrical properties
 - want to interact physically with the sample
- Use WLI/Stylus when you
 - want to measure rough surfaces or step heights $>10 \text{ nm}$
 - want images larger than $100 \mu\text{m}$
 - want fast imaging
 - want easy quantification of heights